



74AHC1G14Q

SINGLE SCHMITT-TRIGGER INVERTER

Description

The DIODES[™] 74AHC1G14Q is an automotive compliant Schmitttrigger inverter gate with a standard push-pull output. The device is designed for operation with a power supply range of 2.0V to 5.5V. The gate performs the positive Boolean function:

$$Y = \overline{A}$$

Features

- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Supply Voltage Range from 2.0V to 5.5V
- ±8mA Output Drive at 4.5V
- CMOS Low-Power Consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time
- Inputs Not Limited by Vcc
- Balanced Propagation Delays
- Balanced Drive Capability
- ESD Protection Tested per AEC-Q100
- Exceeds 2000-V Human Body Model (AEC-Q100-002)
- Exceeds 1000-V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 74AHC1G14Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Applications

- General purpose logics
- Wide array of products, such as:
 - Automotive applications within grade 1 temperature range
 - Industrial computing/controls/automations
 - High reliability networking/communications
 - Industrial/agricultural equipment



Pin Descriptions

Pin Name	Description
NC	No Connection
А	Data Input
GND	Ground
Y	Data Output
Vcc	Supply Voltage

Logic Diagram



Function Table

Input	Output
Α	Y
Н	L
L	Н

Absolute Maximum Ratings (Notes 4 & 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to Vcc + 0.5	V
lıк	Input Clamp Current VI < 0	-20	mA
Іок	Output Clamp Current (Vo < 0 or Vo > Vcc)	±20	mA
lo	Continuous Output Current (Vo = 0 to Vcc)	±25	mA
lcc	Continuous Current Through Vcc	75	mA
I _{GND}	Continuous Current Through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
Tstg	Storage Temperature	-65 to +150	°C
PD	Total Power Dissipation (Note 6)	250	mW

Notes: 4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

5. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

6. This will need to be derated at higher operating temperatures to prevent exceeding maximum T_J. Refer to package thermal characteristics section.



Recommended Operating Conditions (Note 7)

Symbol		Parameter	Min	Max	Unit
Vcc	Operating Voltage	_	2	5.5	V
Vı	Input Voltage		0	5.5	V
Vo	Output Voltage		0	Vcc	V
		Vcc = 2V	_	-50	μA
Iон	High-Level Output Current	$V_{CC} = 3.3V \pm 0.3V$		-4	
		$V_{CC} = 5V \pm 0.5V$	_	-8	mA
		$V_{CC} = 2V$	—	50	μA
IOL	Low-Level Output Current	$V_{CC} = 3.3V \pm 0.3V$	_	4	
		$V_{CC} = 5V \pm 0.5V$	_	8	mA
TA	Operating Free-Air Temperature	_	-40	+125	°C

Note: 7. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (All typical values are at V_{CC} = 3.3V, T_A = +25°C.)

					+25°C		-40°C to	o +85°C	-40°C to	+125°C	
Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
	Desitive Osian land		3V			2.2	—	2.2	_	2.2	V
VT+	/ _{T+} Positive-Going Input Threshold Voltage	—	4.5V			3.15	_	3.15	_	3.15	V
	Threshold Voltage		5.5V		_	3.85	_	3.85		3.85	V
	Negative Caing Input	put	3V	0.9	_		0.9	_	0.9	_	V
VT-	Negative-Going Input Threshold Voltage	—	4.5V	1.35	_	—	1.35	—	1.35	—	V
	Threshold voltage		5.5V	1.65	_		1.65	_	1.65	_	V
	Livetorecia		3V	0.3	_	1.2	0.3	1.2	0.25	1.2	V
ΔVτ	Hysteresis (VT+ - VT-)	—	4.5V	0.4	_	1.4	0.4	1.4	0.35	1.4	V
	(VI+-VI-)		5.5V	0.5	—	1.6	0.5	1.6	0.45	1.6	V
		VI = VIL	2V	1.9	2.0	—	1.9	—	1.9	—	
		іон = -50µА	3V	2.9	3.0	_	2.9	_	2.9	—	
	High Level Output	юн = -зорд	4.5V	4.4	4.5	_	4.4	_	4.4	_	
Vон	Voltage	VI = VIL IOH = -4mA	3V	2.58	_	_	2.48	_	2.40	_	V
		VI = VIL IOH = -8mA	4.5V	3.94		_	3.8	_	3.70	_	
			2V			0.1	_	0.1		0.1	
		$V_I = V_{IH}$	3V			0.1	_	0.1		0.1	
		lo∟ = 50µA	4.5V			0.1	_	0.1		0.1	
Vol	Low Level Output Voltage	$V_I = V_{IH}$ $I_{OL} = 4mA$	3V	_		0.36	_	0.44	_	0.55	V
		VI = VIH IOL = 8mA	4.5V	_		0.36	_	0.44	_	0.55	
lı –	Input Current	$V_I = 5.5V$ or GND	0 to 5.5V	_		±0.1	_	±1	_	±2	μA
Icc	Supply Current	$V_I = 5.5V$ or GND $I_O = 0$	5.5V	_	_	2	_	20	_	40	μA
Cı	Input Capacitance	VI = VCC or GND	5.5V	_	2.0	10	—	10	_	10	pF



Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Мах	Unit
0	Thermal Resistance	SOT25	Nata 0		184		80AN
θја	JA Junction-to-Ambient	SOT353	Note 8		385		°C/W
0	Thermal Resistance	SOT25	Note 0		62		2011
θυς	Junction-to-Case	SOT353	Note 8		164	_	°C/W

Note: 8. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

Vcc = 3.3V ± 0.3V (See Figure 1)

Parameter	From To		Test		+25°C		-40°C to +85°C		-40°C to +125°C		Unit
(Input) (Outp	(Output)	ut) Conditions	Min	Тур	Max	Min	Мах	Min	Max		
4	٨	V	$C_L = 15 pF$	1.0	4.2	12.8	1.0	15.0	1.0	16.5	ns
tpD	A	Ŷ	C _L = 50pF	1.0	6.0	16.3	1.0	18.5	1.0	20.5	ns

$V_{CC} = 5V \pm 0.5V$ (See Figure 1)

Parameter	То			+25°C		-40°C to +85°C		-40°C to +125°C		Unit	
	(Output)	(Output) Conditions	Min	Тур	Max	Min	Max	Min	Max		
t	٨	V	C∟ = 15pF	1.0	3.2	8.6	1.0	10.0	1.0	11.0	ns
tpd	A	Ŷ	C∟ = 50pF	1.0	4.6	10.6	1.0	12.0	1.0	13.5	ns

Operating Characteristics

 $T_A = +25^{\circ}C$

	Parameter	Test Conditions	Vcc = 5V Typ	Unit
Cpd	Power Dissipation Capacitance	f = 1MHz No Load	10	pF



Measurement Information



Vcc	In	puts	V _M	C∟	
100	VI	t _R /t _F	• 141	υL	
3.3V±0.3V	Vcc	≤3ns	V _{CC} /2	15pF	
5V±0.5V	Vcc	≤3ns	Vcc/2	15pF	
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	50pF	
5V±0.5V	Vcc	≤3ns	Vcc/2	50pF	



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non-Inverting Outputs



Notes:

- A. Includes test lead and test apparatus capacitance.
 B. All pulses are supplied at pulse repetition rate ≤ 1MHz.
 C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD} .



Ordering Information (Note 9)



Part Number	Package Package		Package Size	Packing		
Fait Nulliber	Code	(Notes 10 & 11)	Fackage Size	Qty.	Carrier	
74AHC1G14QSE-7	SE	SOT353	2.15mm × 2.1 mm × 1.1 mm 0.65mm lead pitch	3000	7" Tape & Reel	
74AHC1G14QW5-7	W5	SOT25	3.0mm × 2.8mm × 1.2mm 0.95mm lead pitch	3000	7" Tape & Reel	

Notes: 9. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

10. Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html. 11. The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

Marking Information





Part Number	Package	Identification Code
74AHC1G14QW5-7	SOT25	YVQ
74AHC1G14QSE-7	SOT353	YVQ



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



	SOT25				
Dim	Min	Max	Тур		
Α	0.35	0.50	0.38		
В	1.50	1.70	1.60		
С	2.70	3.00	2.80		
D	-	-	0.95		
Н	2.90	3.10	3.00		
J	0.013	0.10	0.05		
К	1.00	1.30	1.10		
L	0.35	0.55	0.40		
М	0.10	0.20	0.15		
Ν	0.70	0.80	0.75		
α	0°	8°	-		
All Dimensions in mm					

(2) Package Type: SOT353





	SOT353				
Dim	Min	Max	Тур		
A1	0.00	0.10	0.05		
A2	0.90	1.00	0.95		
b	0.10	0.30	0.25		
С	0.10	0.22	0.11		
D	1.80	2.20	2.15		
E	2.00	2.20	2.10		
E1	1.15	1.35	1.30		
е	0.650 BSC				
F	0.40	0.45	0.425		
L	0.25	0.40	0.30		
а	0°	8°			
All Dimensions in mm					



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



Dimensions	Value
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

(2) Package Type: SOT353



Dimensions	Value (in mm)
С	0.650
C1	1.900
G	1.300
Х	0.420
X1	1.720
Ý	0.600
Y1	2.500

Mechanical Data

SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.0158 grams (Approximate)

SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.0064 grams (Approximate)



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